NSN 5961-01-066-6359

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-066-6359 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 43.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 290.00 milliamperes all primaries horsepower metric and 1.11 amperes repetitive peak forward current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 81349-mil-s-19500/114 government specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-01-066-6359

Diode Semiconductor Device - Page 2 of 2



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Mil-std (military Standard):

Mil-prf-19500 spec.